

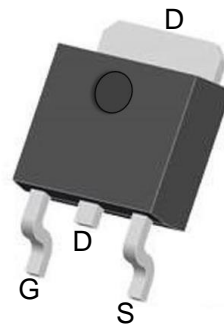
## N-Channel Enhancement Mode Field Effect Transistor

### Features

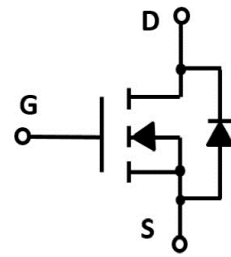
- Excellent package for good heat dissipation
- Ultra low gate charge
- Low reverse transfer capacitance
- Fast switching capability
- Avalanche energy specified

### Application

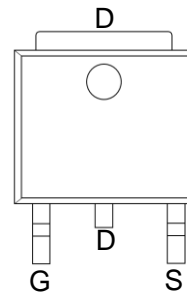
- Power switching application



TO-252 top view



Schematic diagram



Marking and pin assignment

Product Summary		
$V_{DS}$	30	V
$R_{DS(ON)} @ 10V, MAX$	3.5	m $\Omega$
$I_D$	100	A

Absolute Maximum Ratings (TA=25°C unless otherwise noted)				
Symbol	Parameter		Rating	Unit
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
$V_{DS}$	Drain-Source Breakdown Voltage		30	V
$V_{GS}$	Gate-Source Voltage		$\pm 20$	V
$T_J$	Maximum Junction Temperature		150	°C
$T_{STG}$	Storage Temperature Range		-50 to 155	°C
$I_S$	Diode Continuous Forward Current	$T_C=25^\circ C$	100	A
<b>Mounted on Large Heat Sink</b>				
$I_{DM}$	Pulse Drain Current Tested	$T_C=25^\circ C$	400	A
$I_D$	Continuous Drain Current @GS=10V	$T_C=25^\circ C$	100	A
$P_D$	Maximum Power Dissipation	$T_C=25^\circ C$	54	W
$E_{AS}$	Single pulse avalanche energy		100	mJ

<b>Electrical Characteristics (T<sub>J</sub>=25 °C unless otherwise noted)</b>						
<b>Symbol</b>	<b>Parameter</b>	<b>Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25 °C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	VGS=0V, ID=250μA	30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	VDS=30V, VGS=0V	--	--	1	uA
I <sub>GSS</sub>	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	VDS=VGS, ID=250μA	1	--	3	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	VGS=10V, ID=40A	--	3	3.5	mΩ
		VGS=4.5V, ID=30A	--	5	6.5	
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25 °C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	VDS=30V, VGS=0V, f=1MHz	--	2550	--	pF
C <sub>OSS</sub>	Output Capacitance		--	380	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	290	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	VDD=15V, ID=30A, VGS=10V	--	53	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	9	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	13	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	VDD=15V, ID=30A, VGS=10V, RG=12Ω	--	17	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	43	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	110	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	105	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25 °C, I <sub>S</sub> =40A,	--	--	1.2	V

## Typical Operating Characteristics

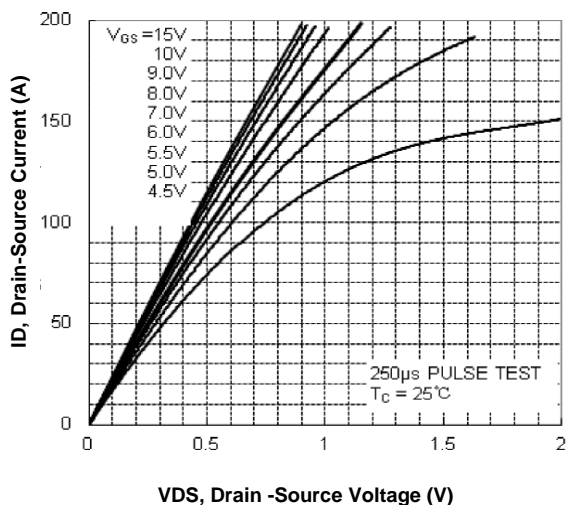


Fig1. Typical Output Characteristics

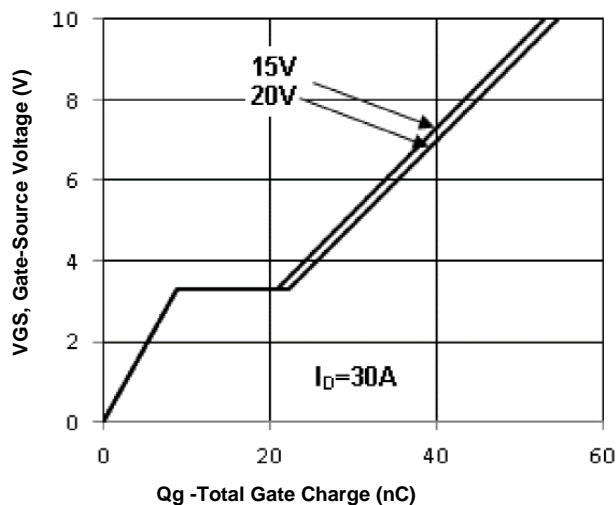


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

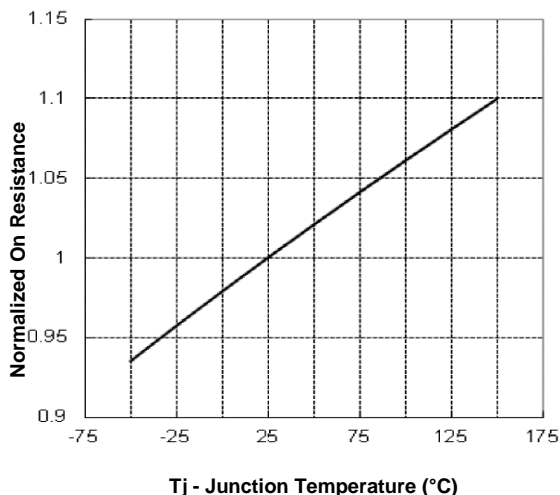


Fig3. Normalized On-Resistance Vs. Temperature

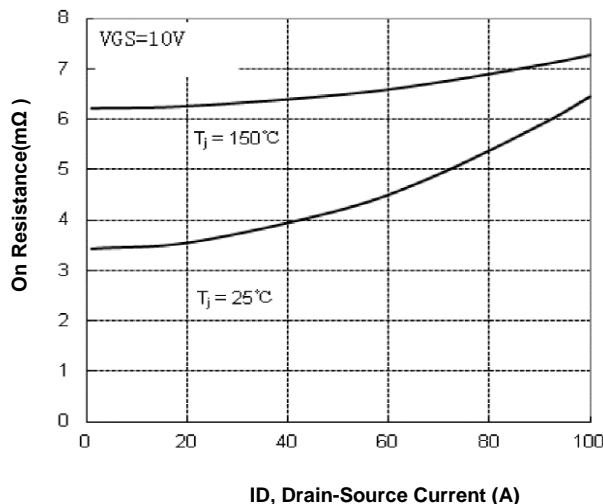


Fig4. On-Resistance Vs. Drain-Source Current

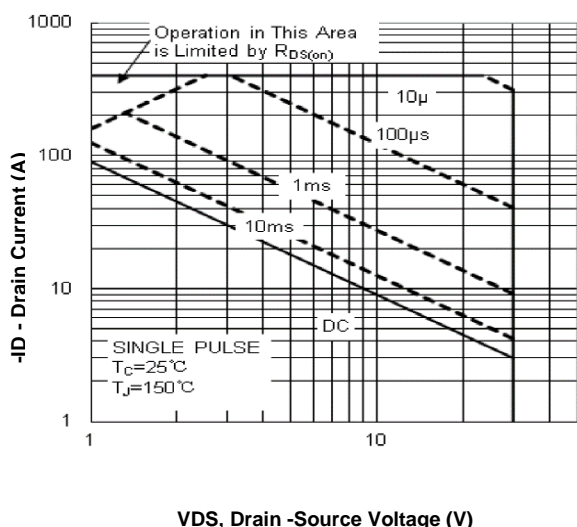


Fig7. Maximum Safe Operating Area

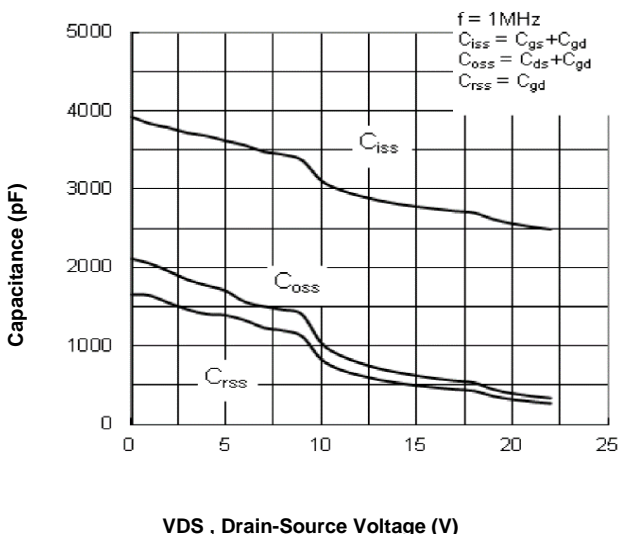
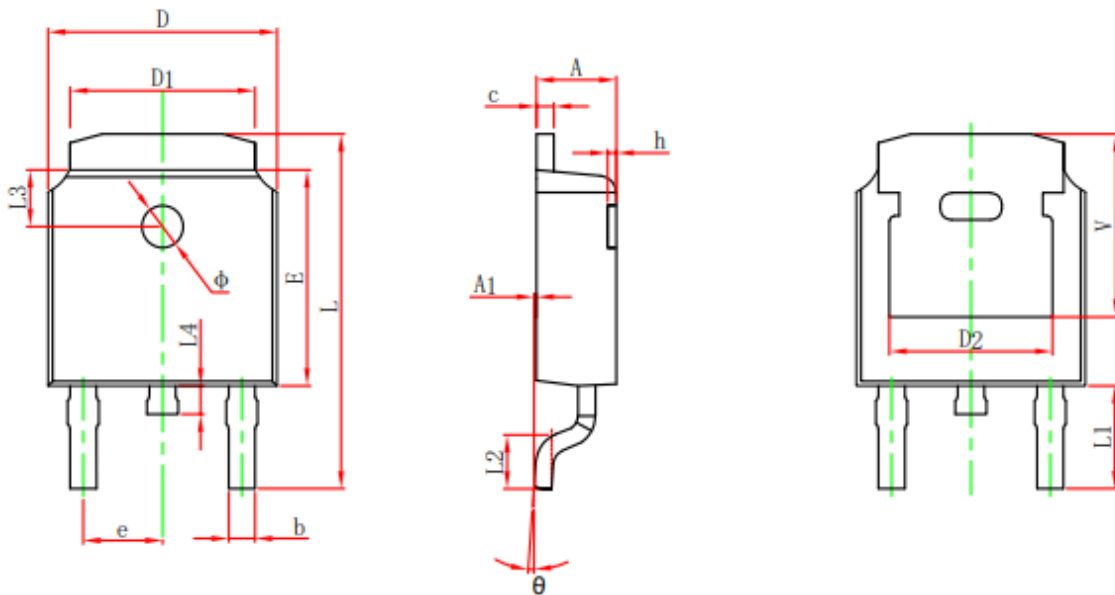


Fig6 Typical Capacitance Vs. Drain-Source Voltage

## TO-252 Package information



Symbol	Dimensions in Millimeters		Dimensions in Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	0.000	0.127	0.000	0.005
b	0.635	0.770	0.025	0.030
c	0.460	0.580	0.018	0.023
D	6.500	6.700	0.256	0.264
D1	5.100	5.460	0.201	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.712	10.312	0.382	0.406
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
h	0.000	0.300	0.000	0.012
V	5.250 REF.		0.207 REF.	

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